Analog Multiplexers/ Demultiplexers

High–Performance Silicon–Gate CMOS

MC54/74HC4051
MC74HC4052
MC54/74HC4053

The MC54/74HC4051, MC74HC4052 and MC54/74HC4053 utilize silicon–gate CMOS technology to achieve fast propagation delays, low ON resistances, and low OFF leakage currents. These analog multiplexers/demultiplexers control analog voltages that may vary across the complete power supply range (from V_{CC} to V_{EE}).

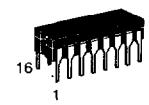
The HC4051, HC4052 and HC4053 are identical in pinout to the metal–gate MC14051B, MC14052B and MC14053B. The Channel–Select inputs determine which one of the Analog Inputs/Outputs is to be connected, by means of an analog switch, to the Common Output/Input. When the Enable pin is HIGH, all analog switches are turned off.

The Channel–Select and Enable inputs are compatible with standard CMOS outputs; with pullup resistors they are compatible with LSTTL outputs.

These devices have been designed so that the ON resistance (R_{on}) is more linear over input voltage than R_{on} of metal–gate CMOS analog switches.

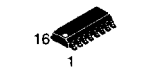
For multiplexers/demultiplexers with channel–select latches, see HC4351, HC4352 and HC4353.

- Fast Switching and Propagation Speeds
- Low Crosstalk Between Switches
- Diode Protection on All Inputs/Outputs
- Analog Power Supply Range ($V_{CC} - V_{EE}$) = 2.0 to 12.0 V
- Digital (Control) Power Supply Range ($V_{CC} - GND$) = 2.0 to 6.0 V
- Improved Linearity and Lower ON Resistance Than Metal–Gate Counterparts
- Low Noise
- In Compliance With the Requirements of JEDEC Standard No. 7A
- Chip Complexity: HC4051 — 184 FETs or 46 Equivalent Gates
  HC4052 — 168 FETs or 42 Equivalent Gates
  HC4053 — 156 FETs or 39 Equivalent Gates



J SUFFIX
CERAMIC PACKAGE
CASE 620–10

N SUFFIX
PLASTIC PACKAGE
CASE 648–08



D SUFFIX
SOIC PACKAGE
CASE 751B–05

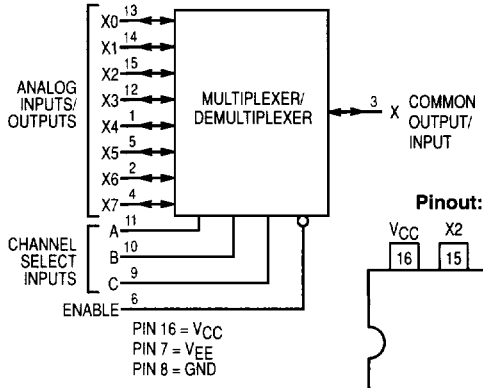
DW SUFFIX
SOIC PACKAGE
CASE 751G–02

DT SUFFIX
TSSOP PACKAGE
CASE 948F–01

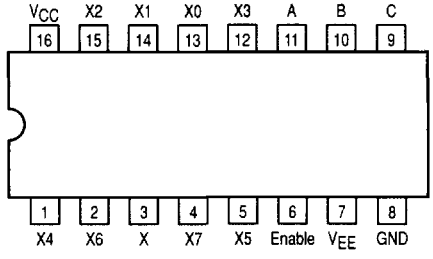
ORDERING INFORMATION

MC54HCXXXXJ	Ceramic
MC74HCXXXXN	Plastic
MC74HCXXXXD	SOIC
MC74HCXXXXDW	SOIC Wide
MC74HCXXXXDT	TSSOP

LOGIC DIAGRAM
MC54/74HC4051
Single–Pole, 8–Position Plus Common Off



Pinout: MC54/74HC4051 (Top View)



FUNCTION TABLE – MC54/74HC4051

Control Inputs				
	Select			
Enable	C	B	A	ON Channels
L	L	L	L	X0
L	L	L	H	X1
L	L	H	L	X2
L	L	H	H	X3
L	H	L	L	X4
L	H	L	H	X5
L	H	H	L	X6
L	H	H	H	X7
H	X	X	X	NONE

X = Don't Care

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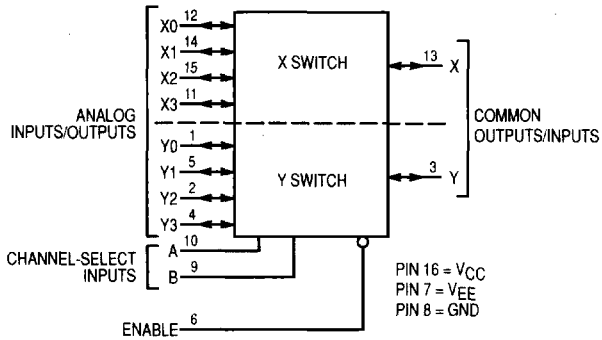
LOGIC DIAGRAM
MC74HC4052
Double–Pole, 4–Position Plus Common Off

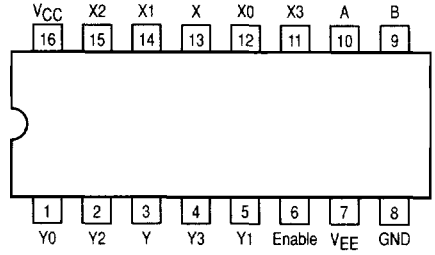


FUNCTION TABLE – MC74HC4052

Control Inputs			
Enable	Select B	Select A	ON Channels
L	L	L	Y0 X0
L	L	H	Y1 X1
L	H	L	Y2 X2
L	H	H	Y3 X3
H	X	X	NONE

X = Don't Care

Pinout: MC74HC4052 (Top View)



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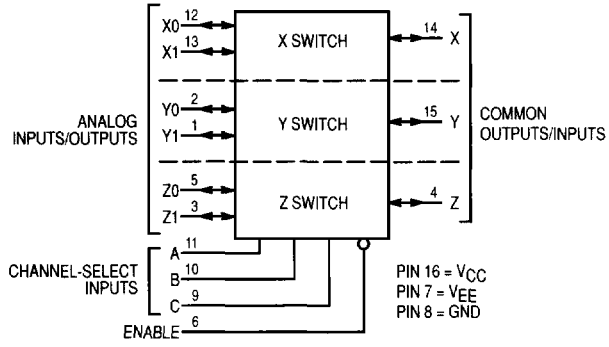
LOGIC DIAGRAM
MC54/74HC4053
Triple Single–Pole, Double–Position Plus Common Off



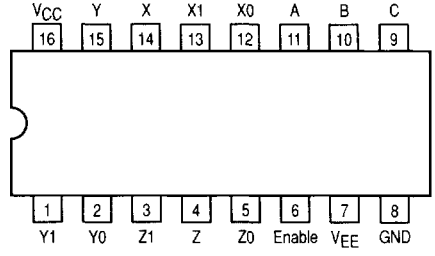
NOTE: This device allows independent control of each switch. Channel–Select Input A controls the X–Switch, Input B controls the Y–Switch and Input C controls the Z–Switch

FUNCTION TABLE – MC54/74HC4053

Control Inputs				
Enable	Select C	Select B	Select A	ON Channels
L	L	L	L	Z0 Y0 X0
L	L	L	H	Z0 Y0 X1
L	L	H	L	Z0 Y1 X0
L	L	H	H	Z0 Y1 X1
L	H	L	L	Z1 Y0 X0
L	H	L	H	Z1 Y0 X1
L	H	H	L	Z1 Y1 X0
L	H	H	H	Z1 Y1 X1
H	X	X	X	NONE

X = Don't Care

Pinout: MC54/74HC4053 (Top View)



MAXIMUM RATINGS*

Symbol	Parameter	Value	Unit
V_{CC}	Positive DC Supply Voltage (Referenced to GND) (Referenced to V_{EE})	– 0.5 to + 7.0 – 0.5 to + 14.0	V
V_{EE}	Negative DC Supply Voltage (Referenced to GND)	– 7.0 to + 5.0	V
V_{IS}	Analog Input Voltage	V_{EE} – 0.5 to V_{CC} + 0.5	V
V_{in}	Digital Input Voltage (Referenced to GND)	– 0.5 to V_{CC} + 0.5	V
I	DC Current, Into or Out of Any Pin	± 25	mA
P_D	Power Dissipation in Still Air, Plastic or Ceramic DIP† SOIC Package† TSSOP Package†	750 500 450	mW
T_{stg}	Storage Temperature Range	– 65 to + 150	°C
T_L	Lead Temperature, 1 mm from Case for 10 Seconds Plastic DIP, SOIC or TSSOP Package Ceramic DIP	 260 300	°C

* Maximum Ratings are those values beyond which damage to the device may occur. Functional operation should be restricted to the Recommended Operating Conditions.

†Derating — Plastic DIP: – 10 mW/°C from 65° to 125°C
Ceramic DIP: – 10 mW/°C from 100° to 125°C
SOIC Package: – 7 mW/°C from 65° to 125°C
TSSOP Package: – 6.1 mW/°C from 65° to 125°C

For high frequency or heavy load considerations, see Chapter 2.

This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high–impedance circuit. For proper operation, V_{in} and V_{out} should be constrained to the range GND ≤ (V_{in} or V_{out}) ≤ V_{CC}.

Unused inputs must always be tied to an appropriate logic voltage level (e.g., either GND or V_{CC}). Unused outputs must be left open.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter		Min	Max	Unit
V_{CC}	Positive DC Supply Voltage (Referenced to GND) (Referenced to V_{EE})		2.0 2.0	6.0 12.0	V
V_{EE}	Negative DC Supply Voltage, Output (Referenced to GND)		– 6.0	GND	V
V_{IS}	Analog Input Voltage		V_{EE}	V_{CC}	V
V_{in}	Digital Input Voltage (Referenced to GND)		GND	V_{CC}	V
V_{IO}*	Static or Dynamic Voltage Across Switch			1.2	V
T_A	Operating Temperature Range, All Package Types		– 55	+ 125	°C
t_r, t_f	Input Rise/Fall Time (Channel Select or Enable Inputs)	V_{CC} = 2.0 V V_{CC} = 4.5 V V_{CC} = 6.0 V	0 0 0	1000 500 400	ns

* For voltage drops across switch greater than 1.2V (switch on), excessive V_{CC} current may be drawn; i.e., the current out of the switch may contain both V_{CC} and switch input components. The reliability of the device will be unaffected unless the Maximum Ratings are exceeded.

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CS — Digital Section (Voltages Referenced to GND) V_{EE} = GND, Except Where Noted

Parameter	Condition	V_{CC} V	Guaranteed Limit –55 to 25°C	≤85°C	≤125°C	Unit
High–Level Input Voltage, Select or Enable Inputs	R_{on} = Per Spec	2.0	1.50	1.50	1.50	V
		4.5	3.15	3.15	3.15	
		6.0	4.20	4.20	4.20	
V_{IL} Maximum Low–Level Input Voltage, Channel–Select or Enable Inputs	R_{on} = Per Spec	2.0	0.3	0.3	0.3	V
		4.5	0.9	0.9	0.9	
		6.0	1.2	1.2	1.2	
I_{in} Maximum Input Leakage Current, Channel–Select or Enable Inputs	V_{in} = V_{CC} or GND, V_{EE} = – 6.0 V	6.0	±0.1	±1.0	±1.0	µA
I_{CC} Maximum Quiescent Supply Current (per Package)	Channel Select, Enable and V_{IS} = V_{CC} or GND; V_{EE} = GND	6.0	2	20	40	µA
	V_{IO} = 0 V V_{EE} = – 6.0	6.0	8	80	160	

NOTE: Information on typical parametric values can be found in Chapter 2.

DC CHARACTERISTICS — Analog Section

Symbol	Parameter	Condition	V_{CC}	V_{EE}	Guaranteed Limit –55 to 25°C	≤85°C	≤125°C	Unit
R_{on}	Maximum "ON" Resistance	V_{in} = V_{IL} or V_{IH}; V_{IS} = V_{CC} to V_{EE}; I_S ≤ 2.0 mA (Figures 1, 2)	4.5	0.0	190	240	280	Ω
			4.5	– 4.5	120	150	170	
			6.0	– 6.0	100	125	140	
		V_{in} = V_{IL} or V_{IH}; V_{IS} = V_{CC} or V_{EE} (Endpoints); I_S ≤ 2.0 mA (Figures 1, 2)	4.5	0.0	150	190	230	
			4.5	– 4.5	100	125	140	
			6.0	– 6.0	80	100	115	
ΔR_{on}	Maximum Difference in "ON" Resistance Between Any Two Channels in the Same Package	V_{in} = V_{IL} or V_{IH}; V_{IS} = 1/2 (V_{CC} – V_{EE}); I_S ≤ 2.0 mA	4.5	0.0	30	35	40	Ω
			4.5	– 4.5	12	15	18	
			6.0	– 6.0	10	12	14	
I_{off}	Maximum Off–Channel Leakage Current, Any One Channel	V_{in} = V_{IL} or V_{IH}; V_{IO} = V_{CC} – V_{EE}; Switch Off (Figure 3)	6.0	– 6.0	0.1	0.5	1.0	µA
	Maximum Off–Channel Leakage Current, Common Channel HC4051	V_{in} = V_{IL} or V_{IH}; V_{IO} = V_{CC} – V_{EE}; Switch Off (Figure 4)	6.0	– 6.0	0.2	2.0	4.0	
	HC4052		6.0	– 6.0	0.1	1.0	2.0	
	HC4053		6.0	– 6.0	0.1	1.0	2.0	
I_{on}	Maximum On–Channel Leakage Current, Channel–to–Channel HC4051	V_{in} = V_{IL} or V_{IH}; Switch–to–Switch = V_{CC} – V_{EE}; (Figure 5)	6.0	– 6.0	0.2	2.0	4.0	µA
	HC4052		6.0	– 6.0	0.1	1.0	2.0	
	HC4053		6.0	– 6.0	0.1	1.0	2.0	

AC CHARACTERISTICS (C_L = 50 pF, Input $t_r = t_f$ = 6 ns)

Symbol	Parameter	V_{CC} V	Guaranteed Limit –55 to 25°C	Guaranteed Limit ≤85°C	Guaranteed Limit ≤125°C	Unit
t_{PLH}, t_{PHL}	Maximum Propagation Delay, Channel–Select to Analog Output (Figure 9)	2.0 4.5 6.0	370 74 63	465 93 79	550 110 94	ns
t_{PLH}, t_{PHL}	Maximum Propagation Delay, Analog Input to Analog Output (Figure 10)	2.0 4.5 6.0	60 12 10	75 15 13	90 18 15	ns
t_{PLZ}, t_{PHZ}	Maximum Propagation Delay, Enable to Analog Output (Figure 11)	2.0 4.5 6.0	290 58 49	364 73 62	430 86 73	ns
t_{PZL}, t_{PZH}	Maximum Propagation Delay, Enable to Analog Output (Figure 11)	2.0 4.5 6.0	345 69 59	435 87 74	515 103 87	ns
C_{in}	Maximum Input Capacitance, Channel–Select or Enable Inputs		10	10	10	pF
$C_{I/O}$	Maximum Capacitance — Analog I/O		35	35	35	pF
	(All Switches Off) — Common O/I: HC4051		130	130	130	
	HC4052		80	80	80	
	HC4053		50	50	50	
	Feedthrough		1.0	1.0	1.0	

NOTE: For propagation delays with loads other than 50 pF, and information on typical parametric values, see Chapter 2.

			Typical @ 25°C, V_{CC} = 5.0 V, V_{EE} = 0 V	
C_{PD}	Power Dissipation Capacitance (Figure 13)*	HC4051	45	pF
		HC4052	80	
		HC4053	45	

* Used to determine the no–load dynamic power consumption: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$. For load considerations, see Chapter 2.

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ADDITIONAL APPLICATION CHARACTERISTICS (GND = 0 V)

Symbol	Parameter	Condition	V_{CC} V	V_{EE} V	Limit* 25°C '51	'52	'53	Unit
BW	Maximum On–Channel Bandwidth or Minimum Frequency Response (Figure 6)	f_{in} = 1MHz Sine Wave; Adjust f_{in} Voltage to Obtain 0dBm at V_{OS}; Increase f_{in} Frequency Until dB Meter Reads –3dB; R_L = 50Ω, C_L = 10pF	2.25	–2.25	80	95	120	MHz
			4.50	–4.50	80	95	120	
			6.00	–6.00	80	95	120	
—	Off–Channel Feedthrough Isolation (Figure 7)	f_{in} = Sine Wave; Adjust f_{in} Voltage to Obtain 0dBm at V_{IS} f_{in} = 10kHz, R_L = 600Ω, C_L = 50pF	2.25	–2.25	–50			dB
			4.50	–4.50	–50			
			6.00	–6.00	–50			
		f_{in} = 1.0MHz, R_L = 50Ω, C_L = 10pF	2.25	–2.25	–40			
			4.50	–4.50	–40			
			6.00	–6.00	–40			
—	Feedthrough Noise. Channel–Select Input to Common I/O (Figure 8)	V_{in} ≤ 1MHz Square Wave (t_r = t_f = 6ns); Adjust R_L at Setup so that I_S = 0A; Enable = GND R_L = 600Ω, C_L = 50pF	2.25	–2.25	25			mV$_{PP}$
			4.50	–4.50	105			
			6.00	–6.00	135			
		R_L = 10kΩ, C_L = 10pF	2.25	–2.25	35			
			4.50	–4.50	145			
			6.00	–6.00	190			
—	Crosstalk Between Any Two Switches (Figure 12) (Test does not apply to HC4051)	f_{in} = Sine Wave; Adjust f_{in} Voltage to Obtain 0dBm at V_{IS} f_{in} = 10kHz, R_L = 600Ω, C_L = 50pF	2.25	–2.25	–50			dB
			4.50	–4.50	–50			
			6.00	–6.00	–50			
		f_{in} = 1.0MHz, R_L = 50Ω, C_L = 10pF	2.25	–2.25	–60			
			4.50	–4.50	–60			
			6.00	–6.00	–60			
THD	Total Harmonic Distortion (Figure 14)	f_{in} = 1kHz, R_L = 10kΩ, C_L = 50pF THD = $THD_{measured} - THD_{source}$ V_{IS} = 4.0V$_{PP}$ sine wave	2.25	–2.25	0.10			%
		V_{IS} = 8.0V$_{PP}$ sine wave	4.50	–4.50	0.08			
		V_{IS} = 11.0V$_{PP}$ sine wave	6.00	–6.00	0.05			

* Limits not tested. Determined by design and verified by qualification.

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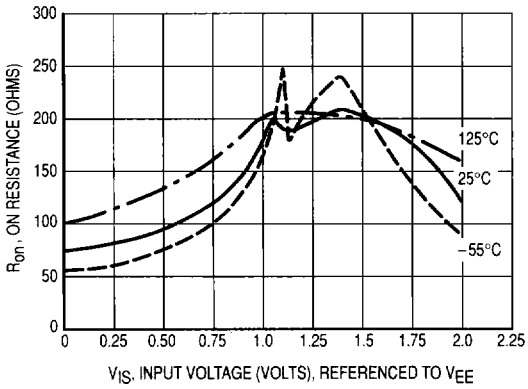

Figure 1a. Typical On Resistance, $V_{CC} - V_{EE} = 2.0$ V

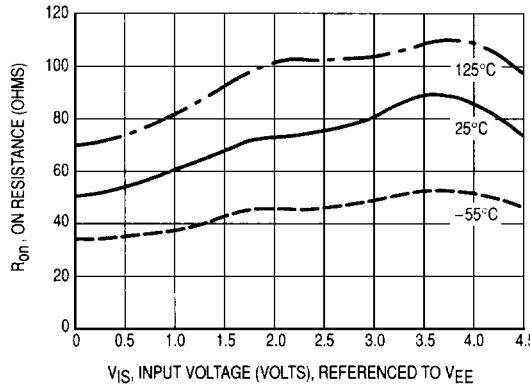

Figure 1b. Typical On Resistance, $V_{CC} - V_{EE} = 4.5$ V

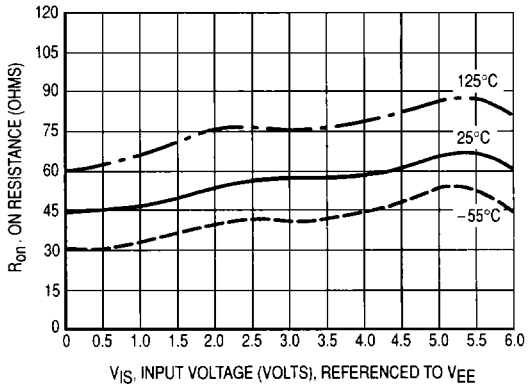

Figure 1c. Typical On Resistance, $V_{CC} - V_{EE} = 6.0$ V

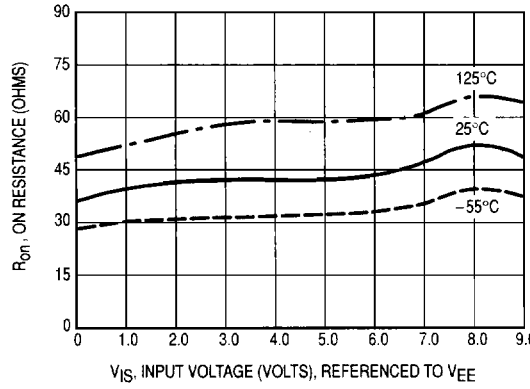

Figure 1d. Typical On Resistance, $V_{CC} - V_{EE} = 9.0$ V

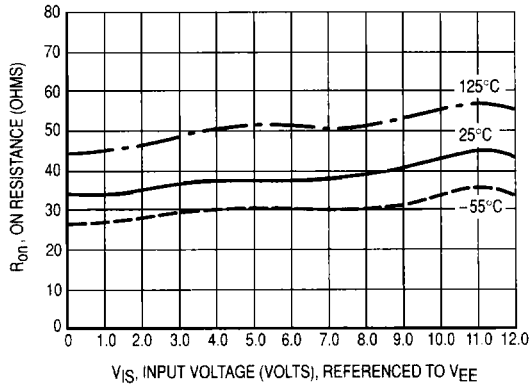

Figure 1e. Typical On Resistance, $V_{CC} - V_{EE} = 12.0$ V

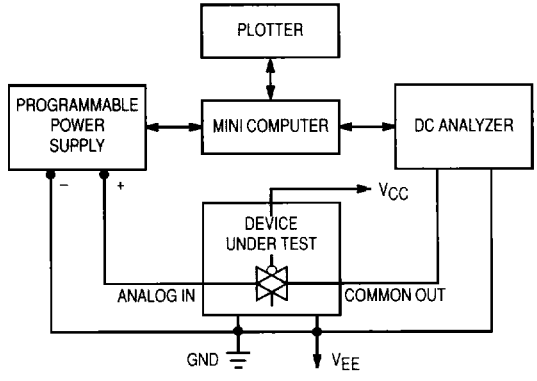

Figure 2. On Resistance Test Set–Up

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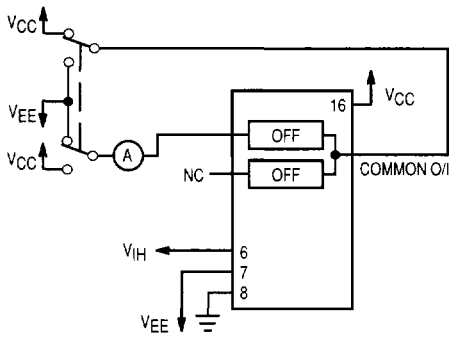


Figure 3. Maximum Off Channel Leakage Current, Any One Channel, Test Set–Up

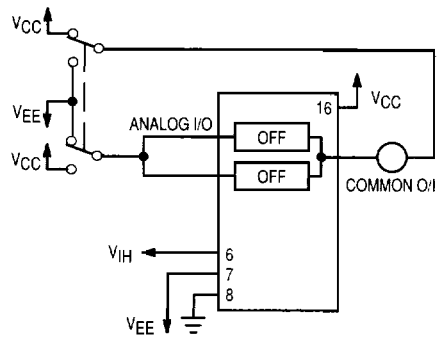


Figure 4. Maximum Off Channel Leakage Current, Common Channel, Test Set–Up

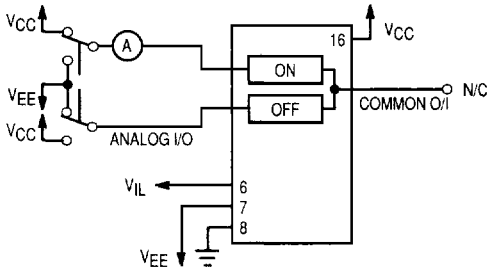


Figure 5. Maximum On Channel Leakage Current, Channel to Channel, Test Set–Up

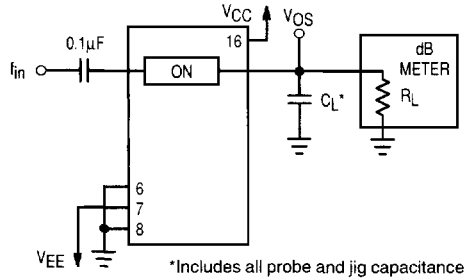


Figure 6. Maximum On Channel Bandwidth, Test Set–Up

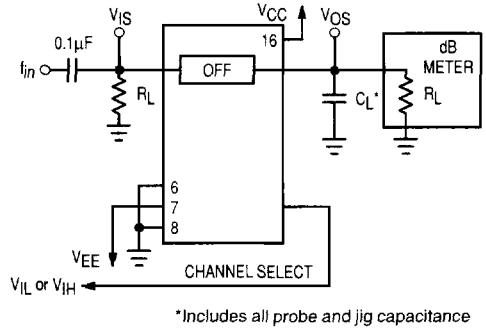


Figure 7. Off Channel Feedthrough Isolation, Test Set–Up

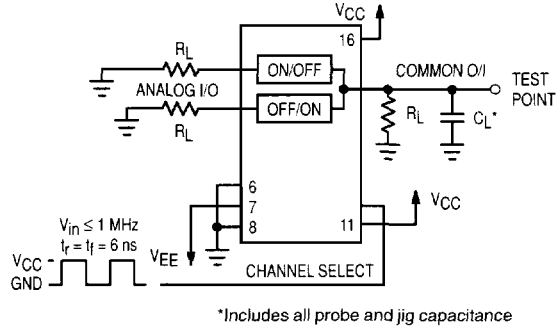


Figure 8. Feedthrough Noise, Channel Select to Common Out, Test Set–Up

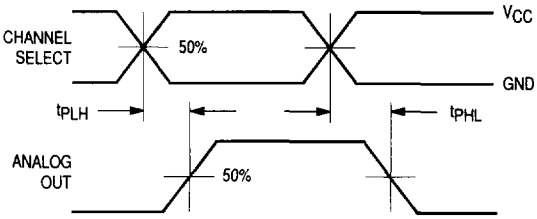
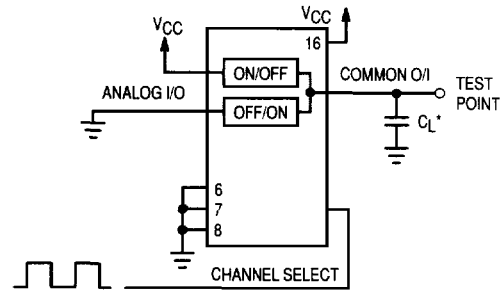


Figure 9a. Propagation Delays, Channel Select to Analog Out



*Includes all probe and jig capacitance

Figure 9b. Propagation Delay, Test Set–Up Channel Select to Analog Out

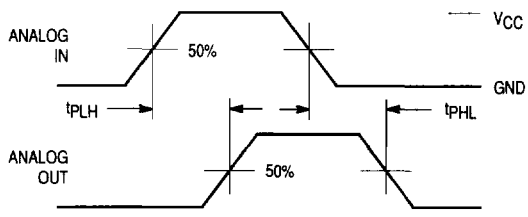
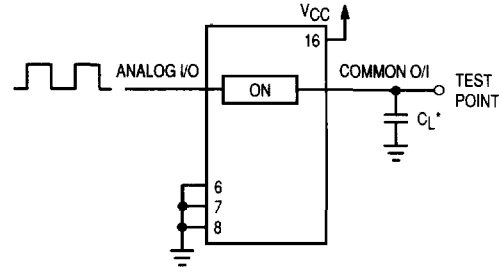


Figure 10a. Propagation Delays, Analog In to Analog Out



*Includes all probe and jig capacitance

Figure 10b. Propagation Delay, Test Set–Up Analog In to Analog Out

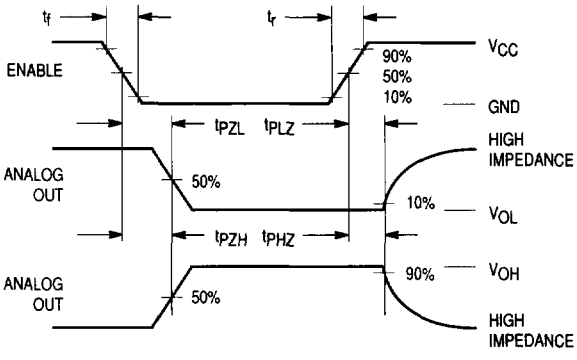


Figure 11a. Propagation Delays, Enable to Analog Out

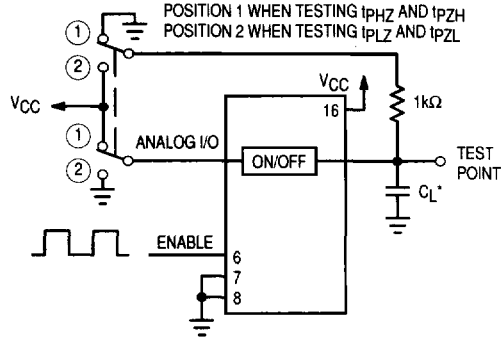
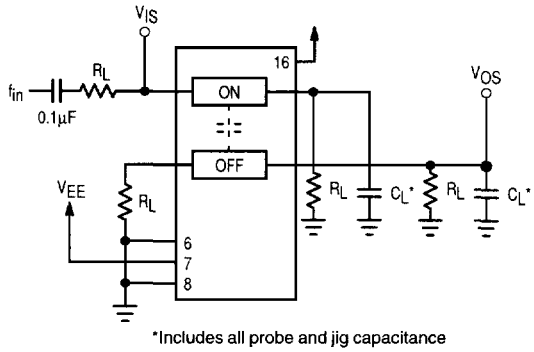


Figure 11b. Propagation Delay, Test Set–Up Enable to Analog Out



*Includes all probe and jig capacitance

Figure 12. Crosstalk Between Any Two Switches, Test Set–Up

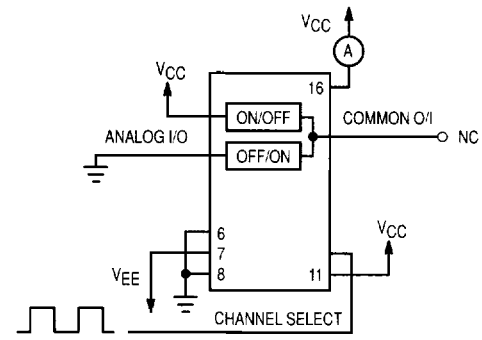
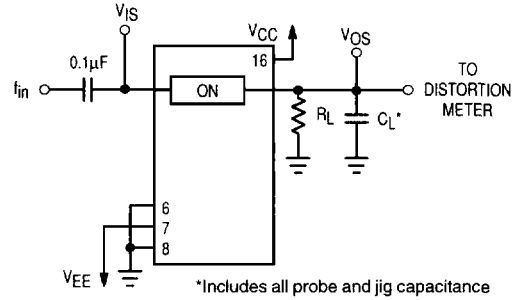


Figure 13. Power Dissipation Capacitance, Test Set–Up



*Includes all probe and jig capacitance

Figure 14a. Total Harmonic Distortion, Test Set–Up

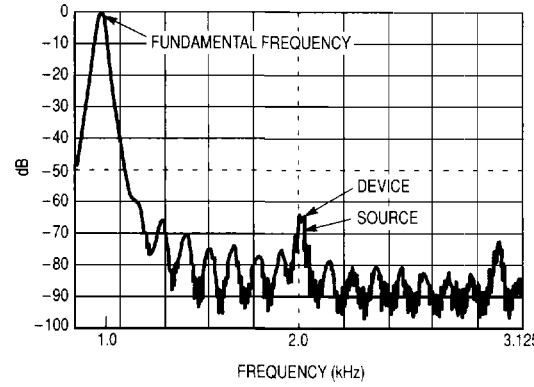


Figure 14b. Plot, Harmonic Distortion

APPLICATIONS INFORMATION

The Channel Select and Enable control pins should be at V_{CC} or GND logic levels. V_{CC} being recognized as a logic high and GND being recognized as a logic low. In this example:

V_{CC} = +5V = logic high
GND = 0V = logic low

The maximum analog voltage swings are determined by the supply voltages V_{CC} and V_{EE}. The positive peak analog voltage should not exceed V_{CC}. Similarly, the negative peak analog voltage should not go below V_{EE}. In this example, the difference between V_{CC} and V_{EE} is ten volts. Therefore, using the configuration of Figure 15, a maximum analog signal of ten volts peak–to–peak can be controlled. Unused analog inputs/outputs may be left floating (i.e., not connected). However, tying unused analog inputs and outputs to V_{CC} or GND through a low value resistor helps minimize crosstalk and feedthrough noise that may be picked up by an unused switch.

Although used here, balanced supplies are not a requirement. The only constraints on the power supplies are that:

V_{CC} – GND = 2 to 6 volts
V_{EE} – GND = 0 to –6 volts
V_{CC} – V_{EE} = 2 to 12 volts
and $V_{EE} \leq$ GND

When voltage transients above V_{CC} and/or below V_{EE} are anticipated on the analog channels, external Germanium or Schottky diodes (D_X) are recommended as shown in Figure 16. These diodes should be able to absorb the maximum anticipated current surges during clipping.

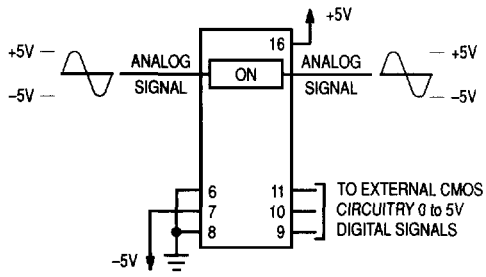


Figure 15. Application Example

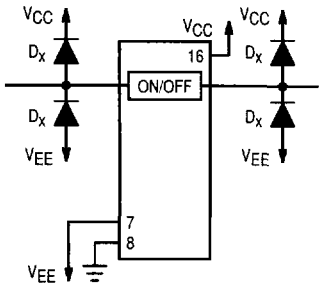
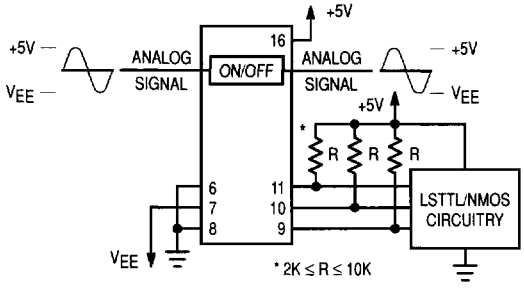
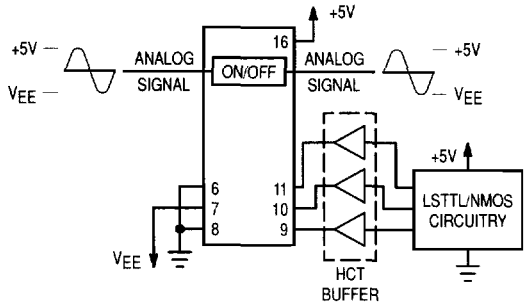


Figure 16. External Germanium or Schottky Clipping Diodes



a. Using Pull–Up Resistors



b. Using HCT Interface

Figure 17. Interfacing LSTTL/NMOS to CMOS Inputs

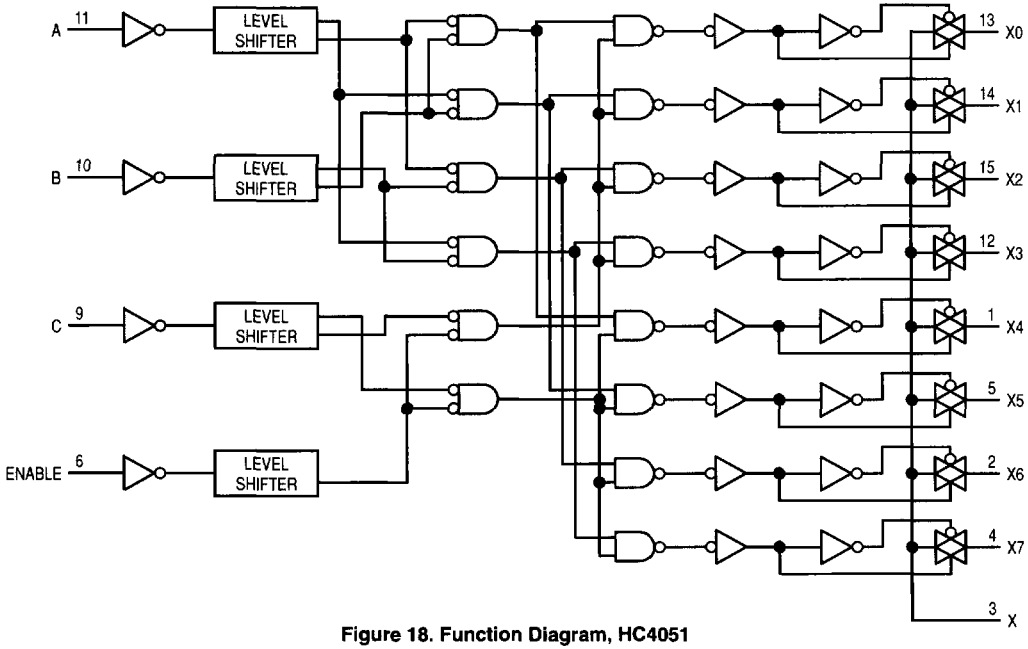


Figure 18. Function Diagram, HC4051

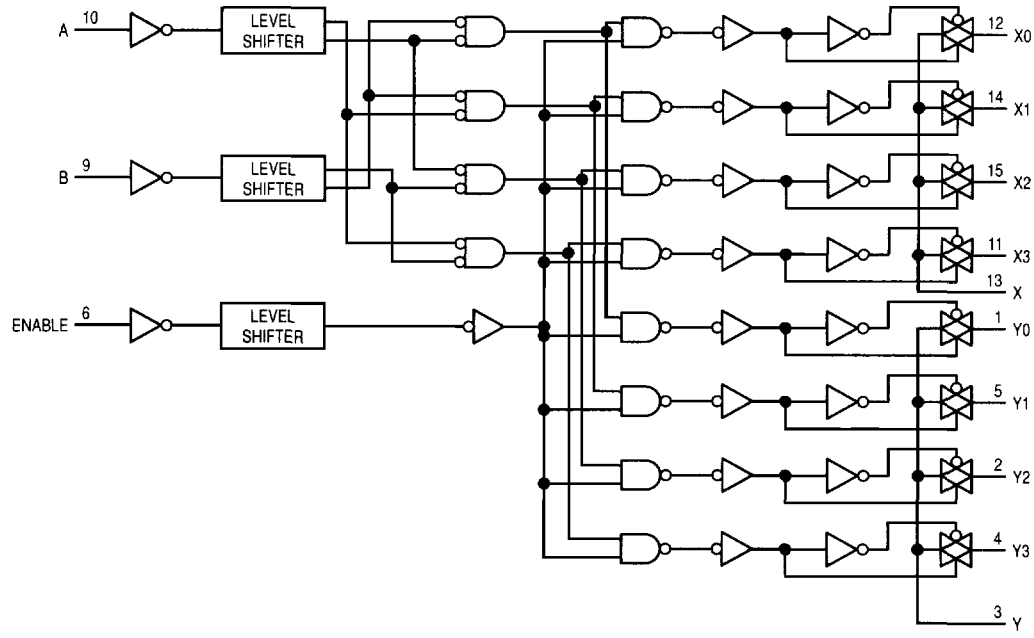


Figure 19. Function Diagram, HC4052

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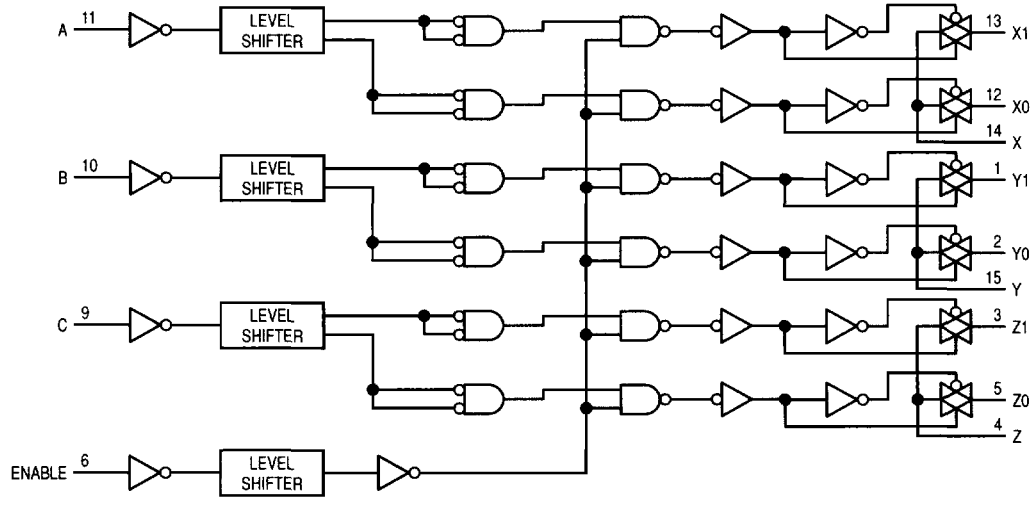

Figure 20. Function Diagram, HC4053